

FGB20N60SF 600V, 20A Field Stop IGBT

Features

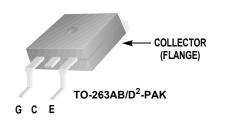
- High Current Capability
- Low Saturation Voltage: V_{CE(sat)} =2.2V @ I_C = 20A
- High Input Impedance
- Fast Switching
- RoHS Compliant

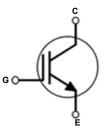
Applications

• Welder, UPS, SMPS, PFC

General Description

Using Novel Field Stop IGBT Technology, Fairchild's new series of Field Stop IGBTs offer the optimum performance for Welder, UPS, SMPS and PFC applications where low conduction and switching losses are essential.





Absolute Maximum Ratings

Symbol	Description		Ratings	Units
V _{CES}	Collector to Emitter Voltage		600	V
V _{GES}	Gate to Emitter Voltage		± 20	V
1.	Collector Current	@ T _C = 25°C	40	A
IC	Collector Current	@ T _C = 100 ^o C	20	A
I _{CM (1)}	Pulsed Collector Current	@ T _C = 25°C	60	A
P _D	Maximum Power Dissipation	@ T _C = 25°C	208	W
۰D	Maximum Power Dissipation	@ T _C = 100 ^o C	83	W
TJ	Operating Junction Temperature		-55 to +150	°C
T _{stg}	Storage Temperature Range		-55 to +150	°C
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C

Notes:

1: Repetitive rating: Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Units
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	-	0.6	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient (PCB Mount)(2)	-	40	°C/W

Notes:

2: Mounted on 1" square PCB(FR4 or G-10 material)

October 2010

Device Marking Device Pa		Package	Rel Size	Таре	Width	Qua	antity	
FGB20N60			O-263AB/D2-PAK	13" Dia		-	800	
Electrical	Char	acteristics of th		5°C unless otherwise noted				
Symbol		Parameter	Test	Conditions	Min.	Тур.	Max.	Units
Off Character	istics							
BV _{CES} C	ollector t	o Emitter Breakdown Vol	tage V _{GE} = 0V, I _C	- = 250μA	600	-	-	V
ΔBV _{CES} Te		ire Coefficient of Breakd			-	0.6	-	V/ºC
-	ollector	Cut-Off Current	V _{CE} = V _{CES}	V _{CE} = V _{CES} , V _{GE} = 0V		-	250	μA
	-E Leaka	age Current	V _{GE} = V _{GES}	-	-	-	±400	nA
						1	1	1
On Character		hold Voltage	I _C = 250μA,	Ver = Ver	4.0	5.0	6.5	V
V _{GE(th)} G		illid voltage	I _C = 200μA,		4.0	2.2	2.8	V
V _{CE(sat)} C	Collector to Emitter Saturation Voltage				-	2.4	-	V
C _{oes} O	put Cap utput Ca	acitance pacitance	V _{CE} = 30V, \ f = 1MHz	/ _{GE} = 0V,	-	940 110	-	pF pF
C _{res} R	everse i	ransfer Capacitance			-	40	-	pF
Switching Ch					1	1	1	1
-()		elay Time			-	13	-	ns
-1	ise Time			$V_{CC} = 400V$, $I_C = 20A$, $R_G = 10\Omega$, $V_{GE} = 15V$, Inductive Load, $T_C = 25^{\circ}C$		16	-	ns
u(011)		elay Time				90	-	ns
-1	all Time					24	48	ns
E _{on} T	urn-On S	witching Loss				0.37	-	mJ
011		witching Loss			-	0.16	-	mJ
		ching Loss			-	0.53	-	mJ
u(01)		elay Time			-	12	-	ns
	ise Time				-	16	-	ns
- (-)		elay Time	$V_{\rm CC} = 400V_{\rm cc}$	I _C = 20A,	-	95	-	ns
	all Time		R _G = 10Ω, V Inductive Lo	$R_G = 10\Omega$, $V_{GE} = 15V$, Inductive Load, $T_C = 125^{\circ}C$		28	-	ns
0.1	urn-On S	witching Loss				0.4	-	mJ
E _{off} T	urn-Off S	witching Loss			-	0.28	-	mJ
E _{ts} To	otal Swite	ching Loss			-	0.69	-	mJ
Q _g To	otal Gate	Charge		1 - 20 4	-	65	-	nC
Q _{ge} G	ate to Er	mitter Charge	V _{CE} = 400V, V _{GE} = 15V	I _C = 20A,	-	7	-	nC
-		ollector Charge				33		

Typical Performance Characteristics Figure 1. Typical Output Characteristics 60 T_C = 25°C 20V 12V 15V 10V Collector Current, I_c [A] 40 20 $V_{GE} = 8V$ 0 0.0 1.5 3.0 4.5 6.0 Collector-Emitter Voltage, V_{CE} [V] Figure 3. Typical Saturation Voltage Characteristics 60

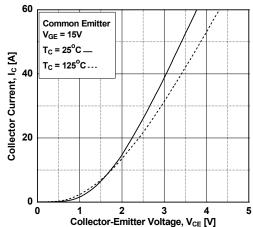


Figure 5. Saturation Voltage vs. Case Temperature at Variant Current Level

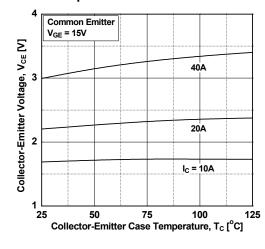


Figure 2. Typical Output Characteristics

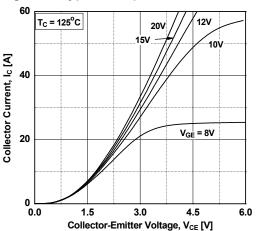


Figure 4. Transfer Characteristics

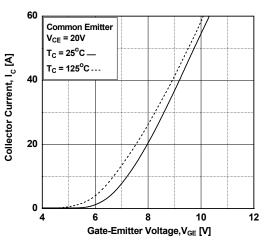
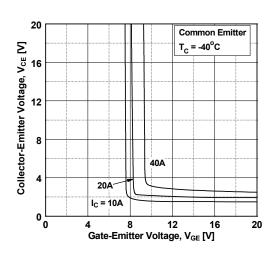
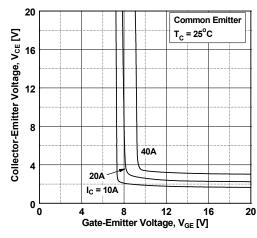


Figure 6. Saturation Voltage vs. V_{GE}

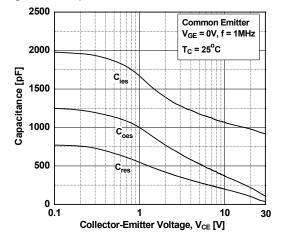


Typical Performance Characteristics

Figure 7. Saturation Voltage vs. V_{GE}









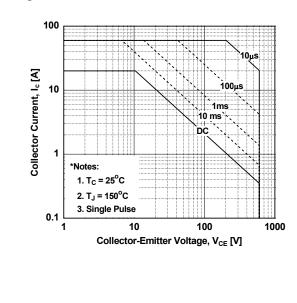


Figure 8. Saturation Voltage vs. V_{GE}

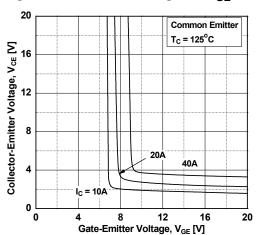


Figure 10. Gate charge Characteristics

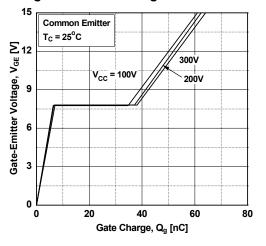
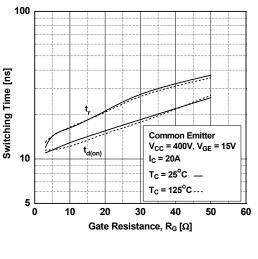
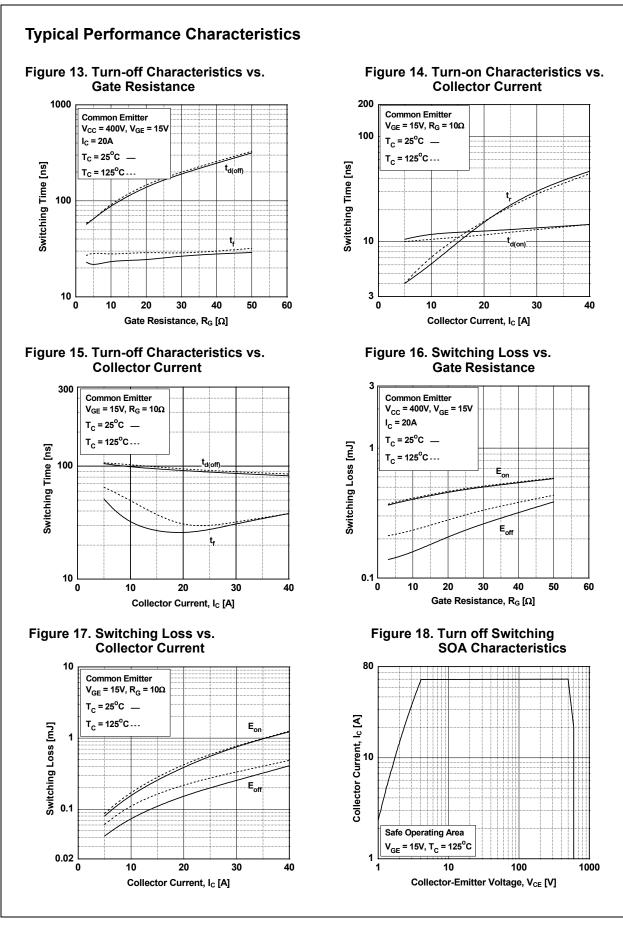
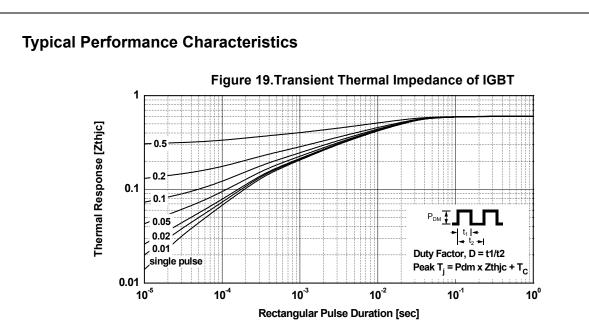
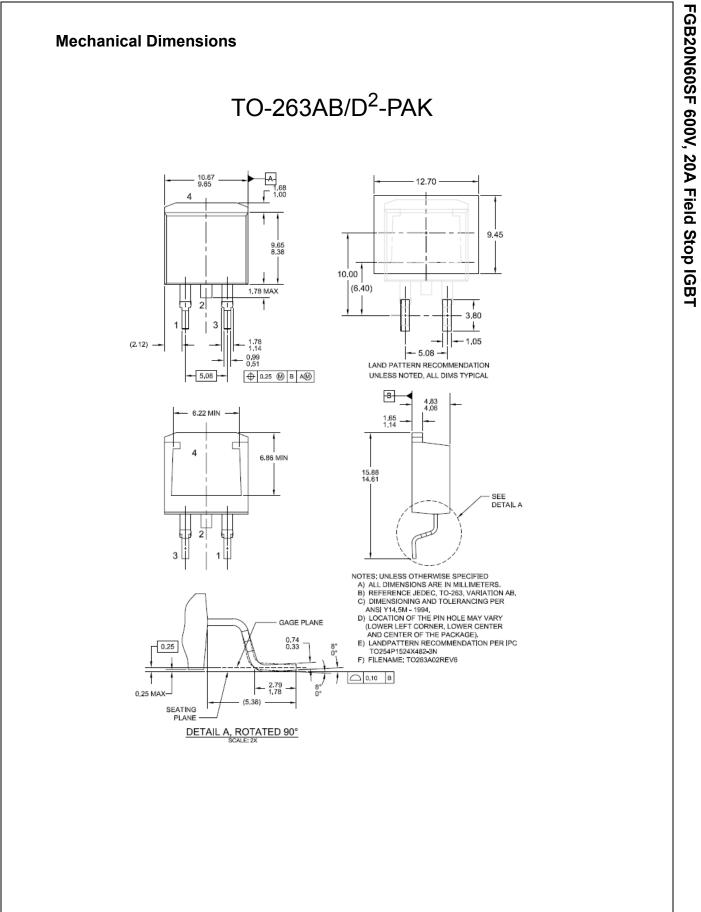


Figure 12. Turn-on Characteristics vs. Gate Resistance











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